

Power Products Division

HIGH AND LOW SIDE DRIVER

The MPIC2112 is a high voltage, high speed, power MOSFET and IGBT driver with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. Logic inputs are compatible with standard CMOS or LSTTL outputs. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates from 10 to 600 volts.

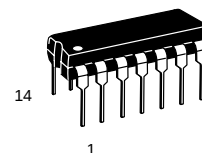
- Floating Channel Designed for Bootstrap Operation
- Fully Operational to +600 V
- Tolerant to Negative Transient Voltage
- dV/dt Immune
- Gate Drive Supply Range from 10 to 20 V
- Undervoltage Lockout for Both Channels
- Separate Logic Supply
- Operating Supply Range from 5 to 20 V
- Logic and Power Ground Operating Offset Range from -5 to +5 V
- CMOS Schmitt-triggered Inputs with Pull-down
- Cycle by Cycle Edge-triggered Shutdown Logic
- Matched Propagation Delay for Both Channels
- Outputs in Phase with Inputs

PRODUCT SUMMARY

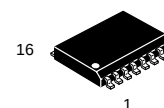
V_{OFFSET}	600 V MAX
$I_{\text{O+/-}}$	200 mA/400 mA
V_{OUT}	10 – 20 V
$t_{\text{on/off}}$ (typical)	125 & 105 ns
Delay Matching	30 ns

MPIC2112

HIGH AND LOW SIDE DRIVER



P SUFFIX
PLASTIC PACKAGE
CASE 646-06



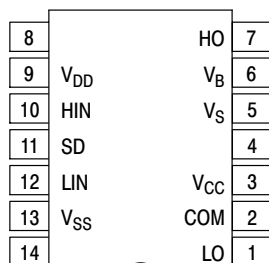
DW SUFFIX
PLASTIC PACKAGE
CASE 751G-02
SOIC – WIDE

ORDERING INFORMATION

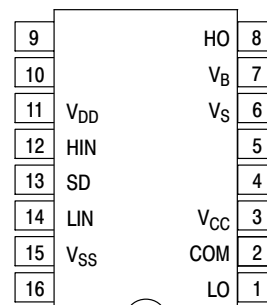
Device	Package
MPIC2112DW	SOIC WIDE
MPIC2112P	PDIP

PIN CONNECTIONS

(TOP VIEW)



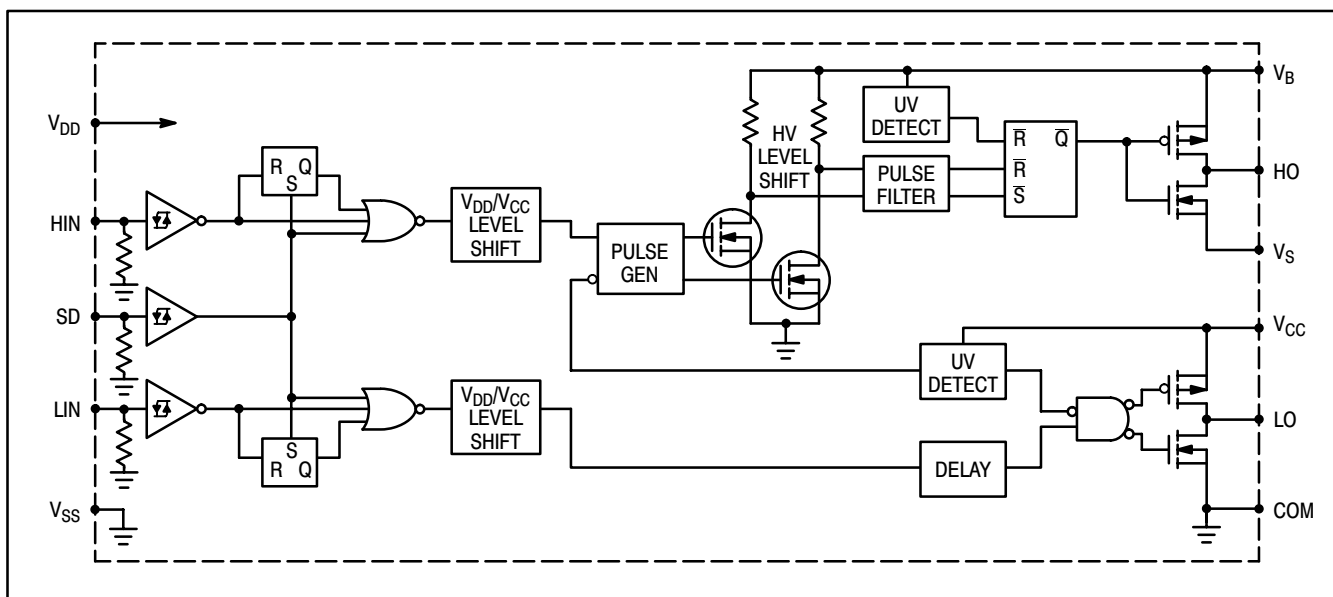
14 LEADS PDIP MPIC2112P



16 LEADS SOIC (WIDE BODY)
MPIC2112DW



SIMPLIFIED BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Rating	Symbol	Min	Max	Unit	
High Side Floating Absolute Voltage	V _B	−0.3	625	V _{DC}	
High Side Floating Supply Offset Voltage	V _S	V _B −25	V _B +0.3		
High Side Floating Output Voltage	V _{HO}	V _S −0.3	V _B +0.3		
Low Side Fixed Supply Voltage	V _{CC}	−0.3	25		
Low Side Output Voltage	V _{LO}	−0.3	V _{CC} +0.3		
Logic Supply Voltage	V _{DD}	−0.3	V _{SS} +25		
Logic Supply Offset Voltage	V _{SS}	V _{CC} −25	V _{CC} +0.3		
Logic Input Voltage (HIN, LIN & SD)	V _{IN}	V _{SS} −0.3	V _{DD} +0.3		
Allowable Offset Supply Voltage Transient	dV _S /dt	−	50	V/ns	
*Package Power Dissipation @ T _A ≤ +25°C	(14 Lead DIP)	P _D	−	1.6	Watt
	(16 SOIC−WIDE)	−	−	1.25	
Thermal Resistance, Junction to Ambient	(14 Lead DIP)	R _{θJA}	−	75	°C/W
	(16 SOIC−WIDE)	−	−	100	
Operating and Storage Temperature	T _J , T _{stg}	−55	150	°C	
Lead Temperature for Soldering Purposes, 10 seconds	T _L	−	260	°C	

RECOMMENDED OPERATING CONDITIONS

The Input/Output logic timing Diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S and V_{SS} offset ratings are tested with all supplies biased at 15 V differential.

High Side Floating Supply Absolute Voltage	V_B	V_S+10	V_S+20	V
High Side Floating Supply Offset Voltage	V_S	Note 1	600	
High Side Floating Output Voltage	V_{HO}	V_S	V_B	
Low Side Fixed Supply Voltage	V_{CC}	10	20	
Low Side Output Voltage	V_{LO}	0	V_{CC}	
Logic Supply Voltage	V_{DD}	$V_{SS}+5$	$V_{SS}+20$	
Logic Supply Offset Voltage	V_{SS}	-5	5	
Logic Input Voltage (HIN, LIN & SD)	V_{IN}	V_{SS}	V_{DD}	
Ambient Temperature	T_A	-40	125	°C

Note 1: Logic operational for V_S of -5 to $+600$ V. Logic state held for V_S of -5 V to $-V_{BS}$.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Typ	Max	Unit
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STATIC ELECTRICAL CHARACTERISTICS – SUPPLY CHARACTERISTICS

V_{BIAS} (V_{CC}, V_{BS}, V_{DD}) = 15 V and V_{SS} = COM unless otherwise specified. The V_{IN}, V_{TH} and I_{IN} parameters are referenced to V_{SS} and are applicable to all three logic input leads: HIN, LIN and SD. The VO and IO parameters are referenced to COM or V_{SS} and are applicable to the respective output leads: HO or LO.

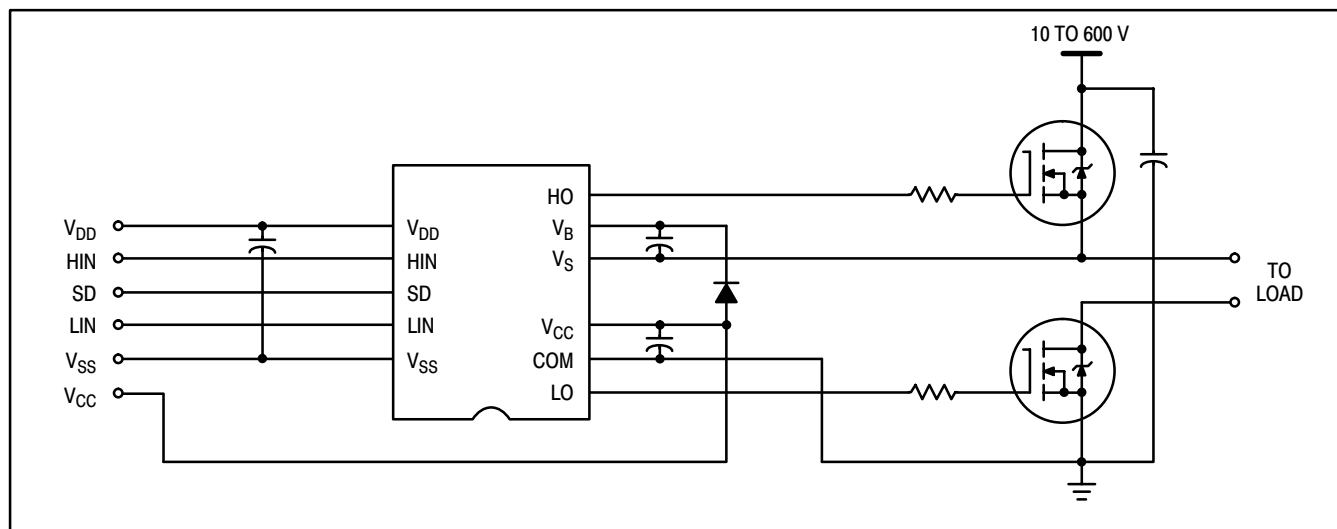
Logic “1” Input Voltage	V _{IH}	9.5	–	–	V
Logic “0” Input Voltage	V _{IL}	–	–	6.0	
High Level Output Voltage, V _{BIAS} –V _O @ V _{IN} = V _{IH} , I _O = 0 A	V _{OH}	–	–	100	mV
Low Level Output Voltage, V _O @ V _{IN} = V _{IL} , I _O = 0 A	V _{OL}	–	–	100	
Offset Supply Leakage Current @ V _B = V _S = 600 V	I _{LK}	–	–	50	μA
Quiescent V _{BS} Supply Current @ V _{IN} = 0 V or V _{DD}	I _{QBS}	–	25	60	
Quiescent V _{CC} Supply Current @ V _{IN} = 0 V or V _{DD}	I _{QCC}	–	80	180	
Quiescent V _{DD} Supply Current @ V _{IN} = 0 V or V _{DD}	I _{QDD}	–	2.0	5.0	
Logic “1” Input Bias Current @ V _{IN} = 15 V	I _{IN+}	–	20	40	
Logic “0” Input Bias Current @ V _{IN} = 0 V	I _{IN–}	–	–	1.0	
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	7.4	–	9.6	V
V _{BS} Supply Undervoltage Negative Going Threshold	V _{BSUV–}	7.0	–	9.2	
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	7.6	–	9.6	
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV–}	7.2	–	9.2	
Output High Short Circuit Pulsed Current @ V _{OUT} = 0 V, V _{IN} = 15 V, PW ≤10 μs	I _{O+}	200	250	–	mA
Output Low Short Circuit Pulsed Current @ V _{OUT} = 15 V, V _{IN} = 0 V, PW ≤10 μs	I _{O–}	420	500	–	

DYNAMIC ELECTRICAL CHARACTERISTICS

V_{BIAS} (V_{CC} , V_{BS} , V_{DD}) = 15 V and V_{SS} = COM unless otherwise specified. T_A = 25°C.

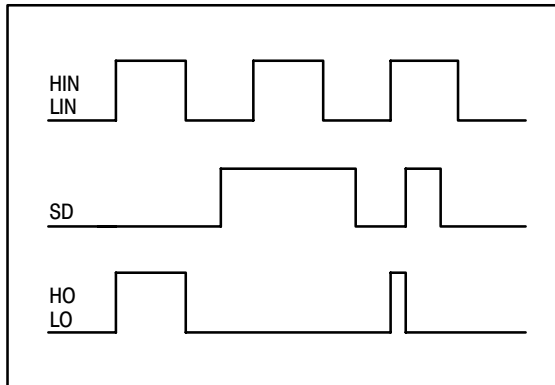
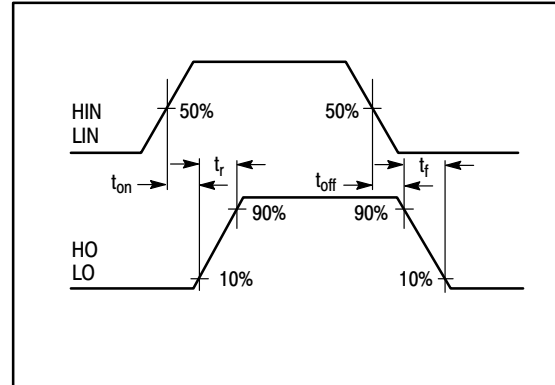
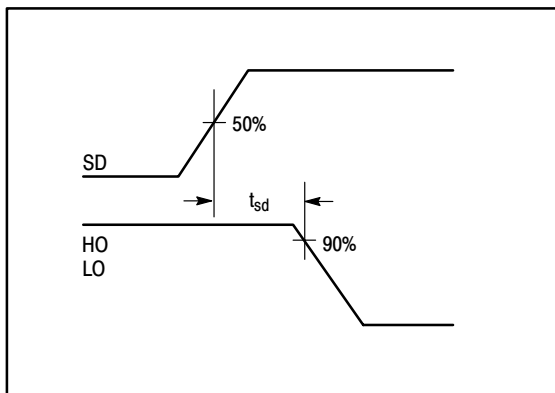
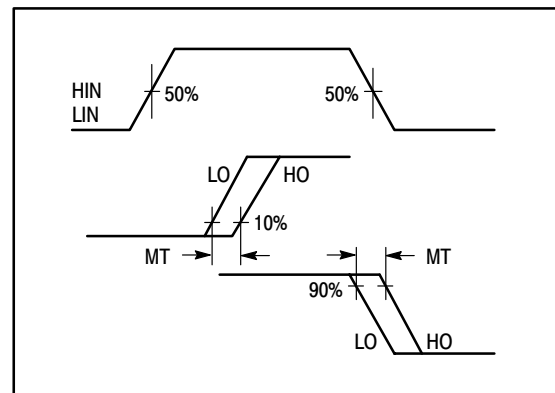
Turn-On Propagation Delay @ $V_S = 0\text{ V}$	t_{on}	–	125	180	ns
Turn-Off Propagation Delay @ $V_S = 600\text{ V}$	t_{off}	–	105	160	
Shutdown Propagation Delay @ $V_S = 600\text{ V}$	t_{sd}	–	105	160	
Turn-On Rise Time @ $C_L = 1000\text{ pF}$	t_r	–	80	130	
Turn-Off Fall Time @ $C_L = 1000\text{ pF}$	t_f	–	40	65	
Delay Matching, HS & LS Turn-On/Off	MT	–	–	30	

TYPICAL CONNECTION

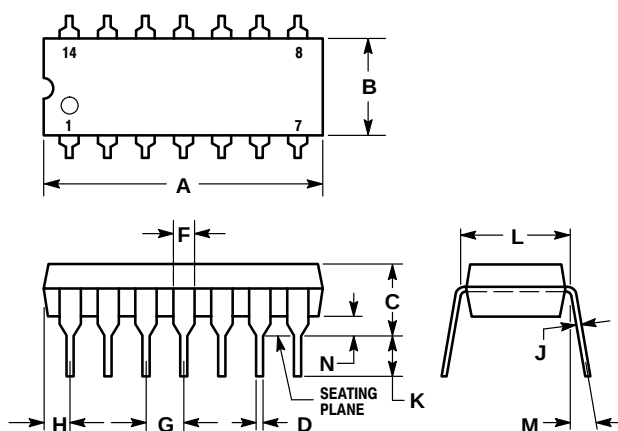


LEAD DEFINITIONS

Symbol	Lead Description
V_{DD}	Logic Supply
HIN	Logic Input for High Side Gate Driver Output (HO), In Phase
SD	Logic Input for Shutdown
LIN	Logic Input for Low Side Gate Driver Output (LO), In Phase
V_{SS}	Logic Ground
V_B	High Side Floating Supply
HO	High Side Gate Drive Output
V_S	High Side Floating Supply Return
V_{CC}	Low Side Supply
LO	Low Side Gate Drive Output
COM	Low Side Return


Figure 1. Input / Output Timing Diagram

Figure 2. Switching Time Waveform Definitions

Figure 3. Deadtime Waveform Definitions

Figure 4. Delay Matching Waveform Definitions

PACKAGE DIMENSIONS

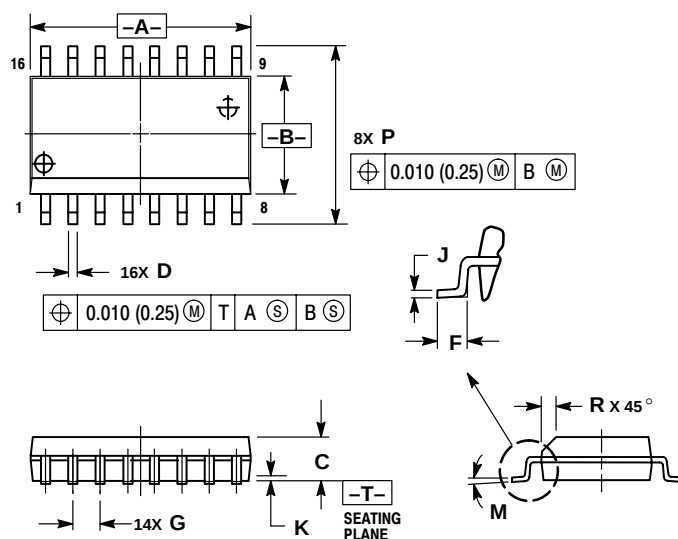


**CASE 646-06
ISSUE L**

NOTES:

1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
4. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	19.56
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.300 BSC		7.62 BSC	
M	0°	10°	0°	10°
N	0.015	0.039	0.39	1.01



**CASE 751G-02
ISSUE A**

NOTES:

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DJM	MIN	MAX	MIN	MAX
A	10.15	10.45	0.400	0.411
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

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